Initial Information Data Sheet

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Application Information

Title Line One::

Callium Nitride Semiconductor Light
Emitting Device Having Multi-Quantum

Title Line Three:: -Well Structure Active Layer, And

Title Line Four:: Semiconductor Laser Light Source Device

Total Drawing Sheets::

Formal Drawings?::

Application Type::

Utility

Docket Number:: 204552016410

Representative Information

Representative Customer Number:: 25227

dc-295426

Continuity Information

This application is a::

> Application One::

Continuation of 09/380,537

Filing Date:: September 2, 1999

which is a:: 371 of

>>Application Two:: PCT/JP98/00828 February 27, 1998

Prior Foreign Applications

Foreign Application One:: JP 9-52596

Filing Date:: March 7, 1997

Country:: Japan Priority Claimed:: Yes

Foreign Application Two:: JP 9-65725

Filing Date:: March 19, 1997

Country:: Japan Priority Claimed:: Yes

dc-295426 2